Synthesis and Crystal Structure of V₁₅Sb₁₈

Sigrid Furuseth[†] and Helmer Fjellvåg

Department of Chemistry, University of Oslo, N-0315 Oslo, Norway

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The 'new' phase $V_{15}Sb_{18}$ has been synthesized as polycrystalline powder and as single crystals by means of chemical transport reactions. V₁₅Sb₁₈ is shown to be the correct formula for the phase described as V₅Sb₄ in the literature, and most probably there exists no phase with a Ti₅Te₄-type crystal structure as assumed earlier. $V_{15}Sb_{18}$ crystallizes in space group P4/nmm with $a = 958.66 \pm 0.05$ and $c = 704.74 \pm 0.05$ pm. Its crystal structure was solved on the basis of single-crystal X-ray diffraction data (R = 0.030). One of the vanadium sites (in position 2c) is half-filled. This special feature was verified for another single crystal which was grown without iodine as transporting agent. According to data for powder samples with different nominal compositions, the phase has no major range of homogeneity. The phase exhibits weak, almost temperature-independent paramagnetism. At high temperatures, $T = 1205 \pm 10$ K, $V_{15}Sb_{18}$ decomposes peritectoidally into VSb₂ and V_{1.4}Sb (NiAs-type). The atomic arrangement shows structural elements typical both for VSb₂ and for V₃Sb (CuAl₂-type and Cr₃Si-type, respectively). Two types of columns of coordination polyhedra running along [001] are identified, columns of V tetrahedra connected by Sb atoms, and columns of distorted, square antiprismatic V-Sb units ($[V_2Sb_8]_n$ chains). The relationship between the antiprismatic building units of $V_{15}Sb_{18}$, VSb₂ and VS₄ is described. The metalmetal bonding is extensive. The V₄ tetrahedra are connected by 'single' V atoms forming a two-dimensional network of V-V close contacts (268-295 pm).

The phase relations in the V-Sb system, in particular for the region around 50 atom % Sb, are more complex than for other 3d-metal antimonides. Typically, phases around the 1:1 composition in transition-metal pnictides either take the MnP-type structure (mainly phosphides and arsenides) or the NiAs-type structure, the latter phases frequently exhibiting a substantial range of non-stoichiometry. There is consensus in the literature that an NiAs-type phase also occurs in the V-Sb system, however, with a composition around $V_{1.4}Sb.^1$

In the V-Sb system the phases V₃Sb,² V₃Sb₂³ (in earlier studies termed V₆Sb₅),⁴ V_{1.4}Sb,^{1.4,5} V₅Sb₄⁶ and VSb₂⁷ have been reported. For all of these, except V₅Sb₄, convincing structure determinations are available. Eberle and Schubert⁶ reported in 1968 the existence of a phase with a composition close to VSb that crystallizes with the Ti₅Te₄-type structure. This phase has later been described as V₅Sb₄ in the literature. Bouwma *et al.*¹ were not able to observe V₅Sb₄ in samples quenched from 1373 K. However, the present reinvestigation of the V-Sb system revealed that for annealing conditions below 1205 K, a phase with unit-cell dimensions closely resembling those earlier reported for V₅Sb₄ is obtained. However, the analysis of the single-crystal X-ray diffraction data showed that the true composition is V₁₅Sb₁₈, and

that the crystal structure actually has no major resemblance to the ${\rm Ti}_5{\rm Te}_4$ -type structure. The present paper reports on the preparation, crystal structure, stability and magnetic properties of ${\rm V}_{15}{\rm Sb}_{18}$.

Experimental

Sample preparation. Samples with composition $V_{0.70} Sb-V_{1.30} Sb$ were prepared by heating weighed amounts of the elements (V, 99.5%, A.D. Mackay; Sb, 99.995% Riedel-de Haën) in evacuated and sealed silica glass ampoules. The samples were first heated at 1200 K for 4 days and at 1125 K for 7 days, then crushed and heated to 1125 K for 7 days before finally being quenched in ice water. Additional samples were prepared, for which either a higher quenching temperature was used (up to 1375 K), or slow cooling (down to room temperature over 3 weeks) was adopted.

Single crystals were grown by chemical vapour transport reaction with iodine as a transport agent. 5 mg I_2 per cm³ ampoule volume was used, the transport distance was 12 cm, and the temperature was 1125 K in the growth zone and 1175 K in the hot part of the ampoule. A multiphase powder sample with nominal composition VSb was used as reactant. Polyhedral single crystals with dimensions up to 3 mm in cross-section and with metallic

[†] To whom correspondence should be addressed.

lustre were obtained. In experiments where no transport agent was used, tiny single crystals (with maximum cross-section 0.1 mm) were obtained in the powder samples after prolonged heat treatment (4 months at 1125 K).

Characterization. All powder samples were characterized by powder X-ray diffraction (PXD), using a Guinier-Hägg camera with Cu $K\alpha_1$ radiation and Si as internal standard. Unit-cell dimensions were obtained by least-squares refinements of PXD data, using the CELLKANT program.⁸

The single crystals were investigated by optical microscopy, and the single crystals, as well as the starting materials, were further analyzed by scanning electron microscopy (SEM) and energy-dispersive X-ray analysis (EDX).

Magnetic susceptibility data were collected at a magnetic field of 500 Oe, between 5 and 325 K with a SQUID magnetometer (MPMS, Quantum Design).

X-Ray intensity data collection. Single-crystal X-ray intensity data were collected with MoKα radiation at 295 K with a Nicolet P3/F diffractometer in the θ -2 θ scan mode. Data were collected for scattering angles up to $2\theta = 70^{\circ}$ at a scan speed of 2.00° min⁻¹. For a single crystal with dimensions $0.1 \times 0.1 \times 0.05$ mm³, grown by chemical transport reaction, 5506 reflections with $I > 3\sigma(I)$ were recorded, giving 835 unique reflections. For a smaller crystal, with dimensions $0.05 \times 0.03 \times$ 0.01 mm³, grown without transport agent, 5432 reflections were similarly measured to give a data set of 782 unique reflections. The intensity data were corrected for Lorentz and polarization effects, absorption, and isotropic extinction. Least-squares refinements were performed, minimizing $\Sigma w(|F_o| - |F_c|)^2$ with weight $w = 1/\sigma^2(F_o)$. For all calculations, the GX program system⁹ was used. Relevant data for the structure analysis are shown in Table 1.

Results and discussion

Phase relations. The PXD data for samples prepared at 1200 K with compositions around VSb were not in accordance with published diffraction patterns for any well described V-Sb phase. For a sample with nominal composition V_{0.9}Sb, no Bragg reflections from any of the phases V₃Sb, V₃Sb₂, V_{1.4}Sb and VSb₂ were observed, and based on microscopy studies the sample was considered to be close to single phase. The diffraction pattern resembled that reported by Eberle and Schubert for V₅Sb₄.⁶ However, the present phase analysis clearly showed that the actual phase has a higher antimony content than $4/9 \times 100$ atom %. Indexing the unknown powder diffraction pattern was simple, and was verified by trial-anderror indexing using the TREOR program, 10 to give a tetragonal unit cell with a = 958.34 + 0.05 and $c = 705.36 \pm 0.05$ pm, with figure of merit, M(20) = 302.11

Table 1. Crystal data.

Compound	V ₁₅ Sb ₁₈
Crystal system	Tetragonal
a/pm	958.66(5)
<i>c</i> /pm	704.74(5)
Cell volume/pm ³	647.7(1)
Space group	P4/nmm (No. 129)
Z	1
$d_{\rm calc}/{\rm g~cm}^{-3}$	7.576(2)
Crystal shape	Polyhedral
Crystal dimensions/mm	$0.1 \times 0.1 \times 0.05$
Linear absorption coefficient	239
μ/cm ⁻¹	
Diffractometer	Nicolet P3/F
Radiation	Mo <i>K</i> α
Scan mode	θ –2 θ
Experimental temperature/K	295
Scan speed/° min ⁻¹	2.00
Scan range/°	0.8–0.8
Background count time/scan time	0.50
2θ -range/ $^{\circ}$	0–70.0
Range of h, k and l	-15 to 15; -15 to 15
	and -12 to 12
No. of collected reflections	6012
No. of observed; $l > 3\sigma(l)$	5506
No. of unique reflections	835
Test reflections	3
Absorption correction	Empirical (DIFABS)
Min. and max. absorption	0.827 and 1.396
correction	
Structure determination	MITHRIL/Fourier
Structure refinement minimizing	$\sum w(F_{\rm o} - F_{\rm c})^2$
Weighting scheme	$w=1/\sigma^2(F_o)$
R	0.030
R_{w}	0.031

Relative integrated intensities (obtained by microdensitometer readings of the Guinier films and the SCANPI program system), ¹² d-values and Miller indices are given in Table 2. Later, it proved possible to obtain single crystals of this new phase by chemical transport reactions, using iodine as the transporting agent, and data from

Table 2. Observed Bragg reflections for $V_{15}Sb_{18}$ as measured by microdensitometer. *d*-values, relative intensities, and Miller indices (hkl).

d/pm	Rel. int.	hkl	<i>d</i> /pm	Rel. int.	hkl
352.3	0.07	002	205.9	0.06	213
330.5	0.39	102	205.1	0.30	421
305.5	0.35	221	193.0	0.29	223
303.2	0.27	310	176.0	0.03	004
291.1	0.48	301	173.2	0.12	104
278.5	0.29	311	169.5	0.15	440
272.1	0.31	212	168.4	0.17	432/502
248.8	1.00	321	167.7	0.27	403
244.3	0.53	222	162.8	0.14	333
239.7	0.21	400	160.1	0.09	531
236.7	0.50	302	159.8	0.10	600
227.0	0.13	401	188.9	0.06	522
226.0	0.15	330	155.7	0.09	601
221.9	0.15	113	153.8	0.08	611
220.8	0.60	411	151.6	0.05	620
210.9	0.26	203			

Atom	Wyckoff position	x	y	Z	U _{iso} a
Sb(1)	2 <i>c</i>	3/4	1/4	1/2	52(3)
Sb(2)	8 <i>i</i>	-0.0835(1)	-0.0835(1)	0.3562(1)	30(2)
Sb(3)	8 <i>i</i>	3/4	-0.0116(1)	0.8165(1)	21(2)
0.46(3) V(1)	2 <i>c</i>	1/4	1/4	0.9239(6)	107(16)
V(2)	2 <i>c</i>	1/4	1/4	0.4103(4)	9(4)
V(3)	4 <i>d</i>	1/2	0	0	18(4)
V(4)	8 <i>i</i>	3/4	0.3900(1)	0.1603(3)	22(3)

Table 3. Refined atomic parameters for $V_{15}Sb_{18}$, space group P4/nmm. Calculated standard deviations in parentheses. Data for one single crystal, grown by chemical transport reaction, are given, see text.

Weissenberg photographs confirmed the unit-cell dimensions.

The obtained unit-cell dimensions resemble (as a multiple cell, double c-axis) those expected for a ${\rm Ti}_5{\rm Te}_4$ -type¹³ phase. Single-crystal data (Weissenberg) for a phase with assumed composition ${\rm V}_5{\rm Sb}_4$ were refined by Eberle and Schubert⁶ in space group I4/m, a=981 and c=350 pm, to yield R=0.33 for a ${\rm Ti}_5{\rm Te}_4$ -type atomic arrangement. The similarities in the powder diffraction pattern, and the poor fit of the observed diffraction intensities to a ${\rm Ti}_5{\rm Te}_4$ -type structure model in the earlier work,⁶ indicate that the phase presently described as ${\rm V}_{15}{\rm Sb}_{18}$ may actually be the phase ${\rm V}_5{\rm Sb}_4$ reported in the literature. During this work it was not possible to obtain any phase with unit-cell dimensions corresponding to literature data for ${\rm V}_5{\rm Sb}_4$.

Based on data from thermal analysis (DTA) and examination of samples quenched from different temperatures, $V_{15}Sb_{18}$ was found to exist up to 1205 ± 10 K. PXD data of samples investigated by DTA and taken out just after the endothermal effect observed at 1205 K, showed that $V_{15}Sb_{18}$ decomposes peritectoidally into $V_{1.4}Sb$ (NiAs-type) and VSb_2 . In addition, some Bragg reflections from the low-temperature phase V_3Sb_2 were observed together with some faint diffraction lines due to $V_{1.5}Sb_{18}$. This shows that during cooling $V_{1.4}Sb$ decomposes eutectoidally into V_3Sb_2 and $V_{1.5}Sb_{18}$; however, the degree of transformation is limited by the rather rapid cooling adopted. These observations fit earlier literature reports and leave $V_{1.4}Sb$ as a high-temperature phase.

Structure determination. A single crystal of good quality, synthesized by iodine vapour transport, was used for structure determination. The diffraction data showed systematic absences for hk0 with h+k=2n+1 and for 0k0 with k=2n+1, suggesting either of the two space groups P4/nmm and P4/n. The structure was solved on the basis of space group P4/nmm. Later tests on solving and refining the structure in the lower-symmetry space group P4/n did not improve the R-factor, leaving P4/nmm as the preferred choice. The major part of the structure was found by application of direct methods (MITHRIL), with difference Fourier syntheses concluding the determination. The atomic parameters and temperature factors are listed in Table 3, and gave R=0.030 and $R_w=0.031$.

EDX analysis was carried out in order to establish whether traces of iodine were incorporated in the single crystals. The analysis was not conclusive because the signals from Sb and I could not be resolved from each other. Therefore, a repeated structure refinement was performed on data collected for a tiny single crystal which was obtained without using iodine as transporting agent. The refinement of the structure for this crystal, which was of somewhat lower quality, gave R = 0.044, $R_{\rm w} = 0.036$, with no significant changes in the atomic parameters. The latter, small crystals, as well as the V and Sb starting materials, were all checked for possible iodine content, but with negative result. It is concluded that the $V_{15}Sb_{18}$ phase does not contain any iodine.

One of the vanadium sites, V(1) (Table 3), turned out to be only partly occupied, 46(3) and 52(3) %, respectively, for the two single crystals. The composition of both crystals, as judged from the structure determinations, is thus $V_{15}Sb_{18}$.

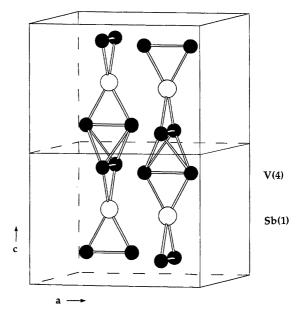


Fig. 1. Schematic representation of $[V(4)_4Sb(1)]_n$ chains in $V_{15}Sb_{18}$. Filled circles, V; open circles, Sb. Two unit cells are shown.

^a $U_{\rm iso} = \frac{1}{3} \sum \sum U_{ii} a_i^* a_i^* a_i a_i$

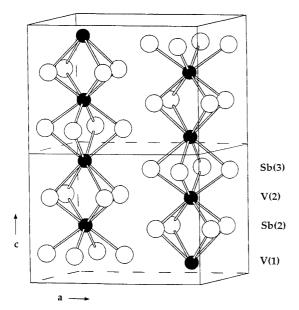


Fig. 2. Schematic representation of $[V(1)V(2)Sb(2)_4Sb(3)_4]_n$ or $[V_2Sb_8]_n$ columns in $V_{15}Sb_{18}$. Filled circles, V; open circles, Sb. Two unit cells are shown.

Atomic arrangement. In the description of the crystal structure, emphasis will be put both on the V-Sb coordination polyhedra and their linking, and on the V-V metal-metal bonding. The crystal structure can, to a first approximation, be described as consisting of two quite different types of columns aligned along the [001] direction. The first type consists of metal tetrahedra formed by the V(4) atoms, which are linked by Sb(1) atoms (Fig. 1). The second type of column consists of approximately square antiprisms of Sb(2) and Sb(3), with alternating V(1) and V(2) atoms in the centers (Fig. 2). The two types of columns are linked by short Sb(3)-V(4) contacts, and in addition via V(3) atoms. Projections of the V sublattice

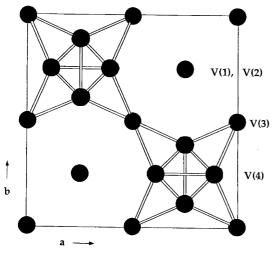


Fig. 3. Projection of the vanadium network (sub-lattice) of $V_{15}Sb_{18}$ on the ab-plane.

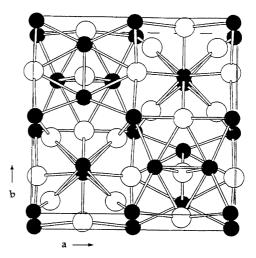


Fig. 4. The crystal structure of $V_{15}Sb_{18}$ as seen along the slightly tilted c-axis. Filled circles, V; open circles, Sb.

and of the crystal structure on the *ab*-plane are shown in Figs. 3 and 4, respectively.

The intra- and intercolumnar V-Sb distances [272.3(4)-299.7(3) pm; Table 4] are all of normal bonding lengths, and may be compared to e.g. 284.9(4) pm in VSb₂.⁷ The Sb-Sb distances larger than 319 pm (Table 4) are considered too long in order to be bonding. The situation for the Sb(2)-Sb(2) bond of 303.6 pm is more uncertain and may be compared with the bonding Sb-Sb distances 289.2(7) pm for the Sb pairs in VSb₂,⁷ and with 285.40,¹⁴ 280.7,¹⁵ and 261.7 pm¹⁵ for the Sb four-rings in the Skutterudite-type antimonides CoSb₃, RhSb₃ and IrSb₃, respectively.

Consideration of the V-V interatomic distances (Table 4) indicates that substantial metal-metal bonding occurs in V₁₅Sb₁₈. The V(4)₄ tetrahedra described above can be considered as integral parts of continuous, two-dimensional nets, formed by V(3) and V(4), with metal-metal interactions existing in the (001) plane. This is illustrated in Fig. 3, where only metal atoms are shown. The V-V interatomic distances are in the range 268.1(1)-

Table 4. Interatomic distances (in pm; d < 360 pm) for $V_{15}Sb_{18}$, with calculated standard deviations in parentheses.

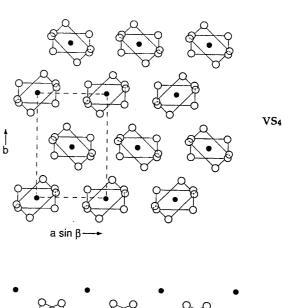
V(1)-4 Sb(3)	292.5(3)	Sb(1)-4 V(4)	274.3(1)
V(1)-4 Sb(2)	299.7(3)	Sb(1)-4 Sb(3)	335.4(1)
V(1)-1 V(2)	342.8(5)	Sb(2)-1 V(3)	275.2(6)
V(2)-4 Sb(3)	278.7(2)	Sb(2)-1 V(2)	279.2(2)
V(2)-4 Sb(2)	279.2(2)	Sb(2)-1 V(1)	299.7(3)
V(2)-1 V(1)	342.8(5)	Sb(2)-2 Sb(2)	303.6(1)
V(3)-4 Sb(3)	272.3(4)	Sb(2)-1 Sb(2)	319.0(1)
V(3)–2 Sb(2)	275.2(6)	Sb(2)-2 Sb(3)	353.6(1)
V(3)-4 V(4)	284.9(3)	Sb(3)-2 V(3)	272.3(4)
V(4)-1 Sb(1)	274.3(1)	Sb(3)-1 V(2)	278.7(2)
V(4)-1 Sb(3)	284.6(1)	Sb(3)-1 V(4)	284.6(1)
V(4)-1 V(4)	268.1(2)	Sb(3)-1 V(1)	292.5(3)
V(4)-2 V(3)	284.9(3)	Sb(3)-4 Sb(3)	322.9(1)
V(4)-2 V(4)	294.9(3)	Sb(3)-2 Sb(2)	353.6(1)
		Sb(3)-1 Sb(1)	335.4(1)

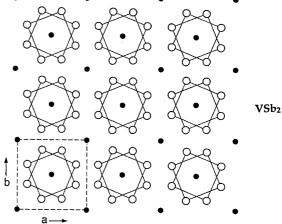
294.9(3) pm, which are comparable with metal-metal distances in e.g. pure vanadium $(262.2 \text{ pm})^{16}$ and VSb_2 (281.9 pm), but significantly longer than the very short chain-forming V-V bonds in the extensive series of vanadium compounds crystallizing in the Cr_3Si (β-W)-type structure, e.g. 247.0 pm in V_3Sb .²

Homogeneity region. The structure determinations for two single crystals, prepared by totally different methods, showed both that the V(1) site is partly occupied (roughly half-filled, Table 3). One may speculate whether the V₁₅Sb₁₈ phase extends over a wide homogeneity interval ranging between $V_{14}Sb_{18}$ [the V(1) site empty] and $V_{16}Sb_{18}$ [the V(1) site fully occupied]. To answer this question, powder samples with different nominal compositions were carefully prepared. The samples consisted in general of two phases. The observed d-values for sets of around 40 Bragg reflections from the V₁₅Sb₁₈ phase were chosen for the least-squares refinements. At the V-rich site of the homogeneity region, a = 958.25 pm, c = 705.15 pm and $V = 647.49 \times 10^6 \text{ pm}^3$, whereas at the Sb-rich side a = 958.64 pm, c = 704.57 pm $V = 647.42 \times 10^6 \text{ pm}^3$ (average for four samples). As most samples contained minor amounts of neighbouring phases, a definite conclusion as to the composition range cannot be given on the basis of the disappearing phase principle. Since the variation of the unit-cell volume is not significant, the content of the unit cell does not vary to any larger extent, but the significant variations in a and c prove that the phase has a certain small homogeneity range. This suggests that the V₁₅Sb₁₈ phase, for some reason, only exists when the V(1) site is about half-filled. Experiments are presently being undertaken with the aim of introducing other types of metal atoms at the V(1) site.

Structural relationships. The emphasis is first put on the square antiprisms as building units, and on the columns which were considered above (Fig. 2). In V₁₅Sb₁₈ and VSb₂ columns of square antiprisms run along the tetragonal axis and are major structural units. In VSb2, which crystallizes in the CuAl₂-type structure, all Sb atoms are situated at the vertices of regular square antiprisms with V atoms in the centers. These antiprisms form columns as in V₁₅Sb₁₈, but in VSb₂ all Sb atoms are shared by two columns, which thereby build the entire structure. In V₁₅Sb₁₈ the antiprisms are not regular (note that one of the V sites is only partly occupied), but more important, they are not connected to build the whole three-dimensional structure. As pointed out above, the three-dimensional structure in V₁₅Sb₁₈ contain two different types of columns plus additional V atoms. Another subtle difference between the square antiprismatic columns in VSb₂ and V₁₅Sb₁₈ concerns the V-V contacts, which in VSb₂ probably are bonding, but in V₁₅Sb₁₈ are non-bonding.

A schematic comparison of the VSb_2 and $V_{15}Sb_{18}$ -type structures is given in Fig. 5, which also includes the crystal structure of VS_4 . The one-dimensional VS_4 -type structure is built by isolated columns of (distorted) square





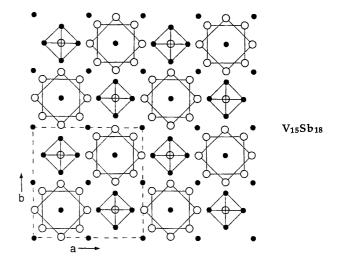


Fig. 5. Schematic representations comparing the crystal structure of VS_4 , the $CuAl_2$ -type structure of VSb_2 , and the $V_{15}Sb_{18}$ -type structure. For explanation, see text. Filled and open circles represent metal (V) and non-metal (S, Sb) atoms, respectively.

antiprisms.¹⁷ In VSb₂ the [V₂Sb₈]_n columns are connected, and are in principle not separate units. However, if the connectivity is neglected and only the columns running through the center of the CuAl₂-type unit cell are represented, the situation illustrated in Fig. 5 is obtained. Along the [110] direction, $[V_2Sb_8]_n$ columns and $[V]_m$ chains, both running along [001], appear alternately. In the corresponding schematic representation of V₁₅Sb₁₈, similar $[V_2Sb_8]_n$ columns (or rather $[V_{1.5}Sb_8]_n$ and $[V]_m$ chains appear in the [110] direction. However, this situation is only found for every second (220) plane. In between, at the (110) planes, chains of [V₄Sb]_n and [V]_m exist. The V₁₅Sb₁₈-type structure can hence be described as a $CuAl_2$ -type structure where $[V_4Sb]_n$ and $[V]_m$ chains are introduced between two-dimensional units of $[V_2Sb_8]_n$ columns and $[V]_m$ chains.

The second notable structure feature of $V_{15}Sb_{18}$ relates to the metal-metal bonding. The characteristic V₄ tetrahedra found in V₁₅Sb₁₈ are also present in the crystal structure of V_3Sb (Cr₃Si or β -W-type, A15),² where they are linked to form strings running parallel to the crystallographic axes. Another characteristic feature of the Cr₃Si-type structure is metal atom strings running in three directions (often discussed in connection with superconductivity in this type of phases). This feature is less pronounced for V₁₅Sb₁₈, where the metal-metal contacts are two-dimensional in nature, and involves the V₄-tetrahedra and the V(3) atoms (Fig. 3). The metal-metal bonding is extensive in the V pnictides. Chains of metal atoms, notably running only in one direction, are generally found for phases with NiAs-type structure. For V_{1.4}Sb¹ the V-V distances in these chains are c/2 = 272.4 pm, whereas for VP the NiAs-type atomic arrangement is very atypical owing to an unusually large axial ratio which gives eight V-V separations (four chains) with d(V-V) between 311.2 and 318.0 pm. ¹⁸ The MnP-type structure of VAs represents a distorted NiAstype structure with a three-dimensional network of V-V contacts, with four d(V-V) in the range 291.3-302.4 pm. 18 In the antimonide V₃Sb₂, the V-V bonding is more extensive, and each V has six metal atom neighbours at separations 245.9 (\times 2), 264.1 (\times 2) and 309.2 $(\times 2)$ pm.

There is no apparent similarity between the crystal structure of $V_{15}Sb_{18}$ and Ti_5Te_4 . The close relation between the geometry of the corresponding unit cells appears to be accidental. However, a comparison of these structures when projected on the ab-plane shows a strik-

ing similarity that may provide an explanation why Eberle and Schubert, on the basis of zero-layer Weissenberg film data, came to the wrong conclusion regarding the crystal structure.

Magnetic properties. The magnetic susceptibility shows a slight temperature dependence between 5 and 300 K. The measured susceptibility, i.e. without performing corrections for the core diamagnetism, decreases from 4.4×10^{-6} emu g⁻¹ at 5 K to 1.7×10^{-6} emu g⁻¹ at 300 K. No evidence for magnetic ordering was found.

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